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### 2.4-2.5 GHz Front-End Module with Internally Matched Power Amplifier, LNA & SP3T Switch

#### **PRODUCTION DATA SHEET**

#### **DESCRIPTION**

LX5553 is a high-integration, high-provides about 25dB power gain, and junction Bipolar Transistor (HBT) included. power amplifier with on chip mode pHEMT (D-pHEMT) single- current with a single 3.6V supply. pole triple-throw (SP3T) switch, all footprint. LX5553 provides capability high of sharing a single antenna between compression point (IP<sub>1dB</sub>) of +29dBm. WLAN and Bluetooth systems through the SP3T switch.

monolithic on-chip output power detector, and and 82mA bias current, the Tx path

performance WLAN front-end module +17dBm linear output power, with (FEM) for 802.11b/g/n and other EVM (<3%) for 64QAM/ 54Mbps applications in the 2.4-2.5GHz OFDM. Both gain and power are frequency range. LX5553 integrates readily measured at antenna port, with an advanced InGaP/GaAs Hetero- the insertion loss of the SP3T switch

The Rx path of LX5553 features impedance matching, a fully matched 13dB small-signal gain, noise figure of low noise amplifier based on InGaAs 2.1dB, and high input referred third-Enhancement mode pseudo-morphic order harmonic intercept point (IIP3) of high electron mobility transistor (E- +5dBm, including the SP3T switch loss. pHEMT) technology, and a Depletion The LNA consumes about 11mA

The Bluetooth path of LX5553 into a single package with 3x3mm features low insertion loss of 0.9dB and input referred 1dB

LX5553 is available in a 16-pin, low profile of 0.55mm, 3x3mm<sup>2</sup> micro-lead The Tx path of LX5553 features a package (MLPQ-16L) in very low microwave profile of 0.55mm. With its high level integrated circuit (MMIC) power of functional integration, best-class amplifier with active bias circuitry, performance, compact footprint and low profile, LX5553 offers an ideal front- $50\Omega$  input/output matching inside the end solution for the ever demanding package. With 3.6V supply voltage design requirements of today's highly integrated mobile equipments, including 802.11b/g/n and Bluetooth applications.

IMPORTANT: For the most current data, consult MICROSEM's website: http://www.microsemi.com

#### **KEY FEATURES**

- 2.4-2.5GHz 802.11b/g/n Front-End Solution in a Single MLP Package
- SP3T for Sharing Antenna between WLAN and Bluetooth
- All RF I/O Matched to 50  $\Omega$
- Single-Supply Voltage 3.0V to 4.2V
- Small Footprint: 3x3mm<sup>2</sup>
- Low Profile: 0.55mm
- RoHS Compliant & Pb-Free

#### TX Features :

- Power Gain ~ 25 dB\*
- Pout ~ +17 dBm\* for 3% EVM at Antenna
- Current ~145 mA at +17 dBm\*
- Pout ~ +21 dBm\* for 11b 1Mbps **DSSS Mask Compliance**
- Quiescent Current ~ 82 mA

#### **RX Features:**

- Gain ~ 13 dB\*
- Noise Figure ~ 2.1 dB\*
- IIP3 ~ +5 dBm\*

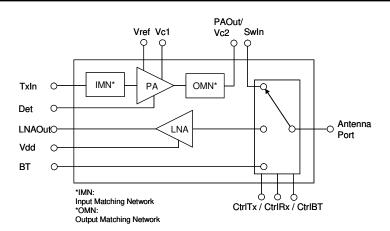
#### Bluetooth Path:

- Insertion Loss ~ 0.9 dB
- IP1dB ~ +29 dBm
- \* Including SP3T switch loss

#### **APPLICATIONS**

- IEEE 802.11b/g/n
- Mobile Phone WLAN module

#### **BLOCK DIAGRAM**



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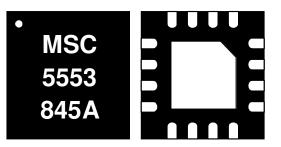
#### Microsemi



2.4-2.5 GHz Front-End Module with Internally Matched Power Amplifier, LNA & SP3T Switch

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#### PRODUCT HIGHLIGHT



#### PACKAGE ORDER INFO

LU

Plastic MLPQ 16 pin 3x3mm RoHS Compliant /Pb-Free

LX5553LU

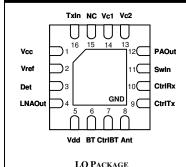
Note: Available in Tape & Reel. Append the letters "TR" to the part number. (i.e. LX5553LU-TR)

#### **ABSOLUTE MAXIMUM RATINGS**

DC Supply Voltage, RF off	5V
Collector Current (PA)	
Drain Current (LNA)	40mA
Total Power Dissipation	2W
RF Input Power (TxIn)	
RF Input Power (Ant, SwIn, BT)	+25 dBm
Maximum Junction Temperature (Tj max)	+150°C
Operation Ambient Temperature	$40^{\circ}$ C to +85°C
Storage Temperature	65°C to $+150$ °C
RoHS/Pb-Free Peak Package Temp. for Solder Reflow	
(40 seconds maximum exposure)	260°C (+0, -5)

Note: Exceeding these ratings could cause damage to the device. All voltages are with respect to Ground. Currents are positive into, negative out of specified terminal.

#### PACKAGE PIN OUT



LQ PACKAGE ("See-Through" View from Top)

RoHS/Pb-free 100% Matte Tin Lead finish

#### THERMAL DATA

LU Plastic MLPQ 16-Pin

THERMAL RESISTANCE-JUNCTION TO CASE, $\theta_{JC}$	10 C/W
THERMAL RESISTANCE-JUNCTION TO AMBIENT, $\theta_{JA}$	50 C/W

Junction Temperature Calculation:  $T_J = T_A + (P_D \times \theta_{JA})$ .

The  $\theta_{JA}$  numbers are guidelines for the thermal performance of the device/pc-board system. All of the above assume no ambient airflow.

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#### Microsemi



# 2.4-2.5 GHz Front-End Module with Internally Matched Power Amplifier, LNA & SP3T Switch

PRODUCTION DATA SHEET

Thank you for your interest in Microsemi® Analog Mixed Signal products.

The full data sheet for this device contains proprietary information.

To obtain a copy, please contact your local Microsemi sales representative. The name of your local representative can be obtained at the following link <a href="http://www.microsemi.com/contact/contactfind.asp">http://www.microsemi.com/contact/contactfind.asp</a>

or

Contact us directly by sending an email to: <a href="mailto:1964ctasheets@microsemi.com">IPGdatasheets@microsemi.com</a>

Be sure to specify the data sheet you are requesting and include your company name and contact information and or yeard.

We look forward to hearing from you.